

BUL39D

High voltage fast-switching NPN power transistor

Features

- Integrated antiparallel collector-emitter diode
- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Application

Electronic transformer for halogen lamp

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds while maintaining the wide RBSOA. The device is designed for use in electronic transformer for halogen lamp.

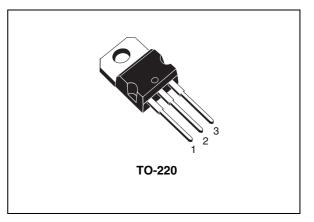


Figure 1. Internal schematic diagram

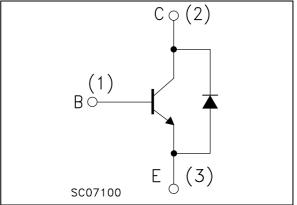


Table 1.Device summary

Order code	Marking	Package	Packaging
BUL39D	BUL39D	TO-220	Tube

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1 Electrical ratings

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	850	V
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	450	V
V _{EBO}	Emitter-base voltage (I _C = 0)	9	V
Ι _C	Collector current	4	А
I _{CM}	Collector peak current (t _P < 5 ms)	8	А
۱ _B	Base current	2	А
I _{BM}	Base peak current (t _P < 5 ms)	4	А
P _{tot}	Total dissipation at $T_c = 25 \ ^{\circ}C$	70	W
T _{stg}	Storage temperature	-65 to 150	°C
Τ _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Max value	Unit
R _{thj-case}	Thermal resistance junction - case	1.8	°C/W



2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

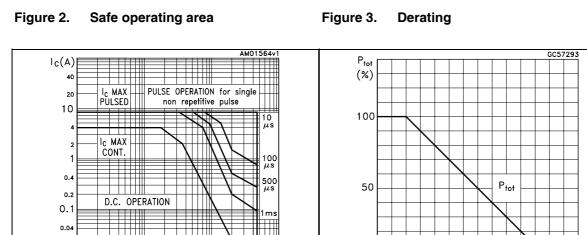
Table 4.								
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit		
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 850 V V _{CE} = 850 V T _C = 125 °C			100 500	μA μA		
I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} = 9 V			100	μA		
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C =100 mA	450			V		
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 1 A \qquad I_{B} = 0.2 A I_{C} = 2.5 A \qquad I_{B} = 0.5 A$			0.5 1.1	V V		
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{C} = 1 A \qquad I_{B} = 0.2 A I_{C} = 2.5 A \qquad I_{B} = 0.5 A$			1.1 1.3	V V		
h _{FE} ⁽¹⁾	DC current gain	$ I_{C} = 10 \text{ mA} \qquad V_{CE} = 5 \text{ V} \\ I_{C} = 5 \text{ A} \qquad V_{CE} = 10 \text{ V} $	10 4					
t _s t _f	Inductive load Storage time Fall time	$I_{C} = 2.5 \text{ A}$ $V_{clamp} = 300 \text{ V}$ $I_{B1} = 0.5 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$			1.5 0.1	μs μs		
V _F	Diode forward voltage	$R_{BB} = 0$ L=1 mH I _F = 2 A			1.5	V		

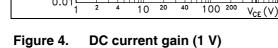
 Table 4.
 Electrical characteristics

1. Pulsed duration = 300 ms, duty cycle $\leq 1.5\%$



Electrical characteristics (curves) 2.1

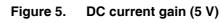




4

20 40

0.02 0.01



50

100

T_C (°C)

0

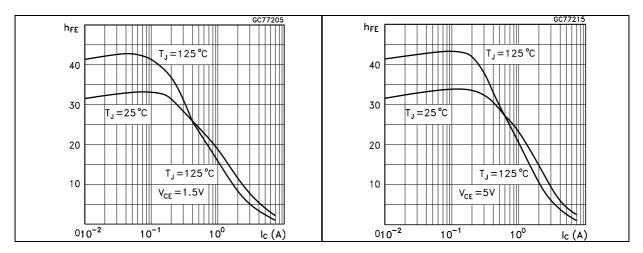


Figure 6. Collector emitter saturation voltage Figure 7. Base emitter saturation voltage

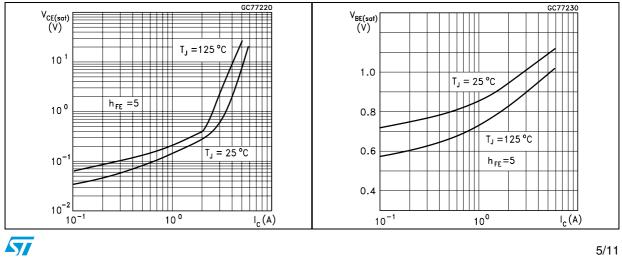


Figure 8. Inductive load fall time

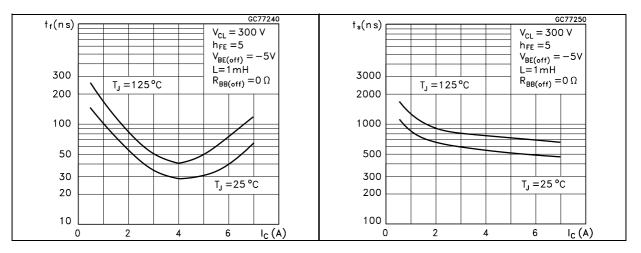


Figure 10. Reverse biased safe operating area

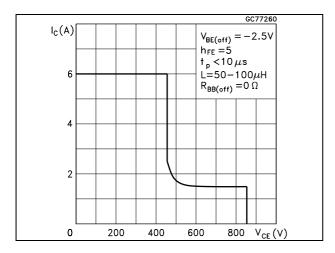


Figure 9. Inductive load storage time



3 Test circuit

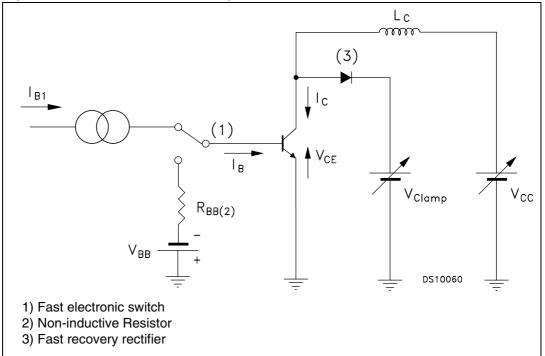


Figure 11. Inductive load switching test circuit

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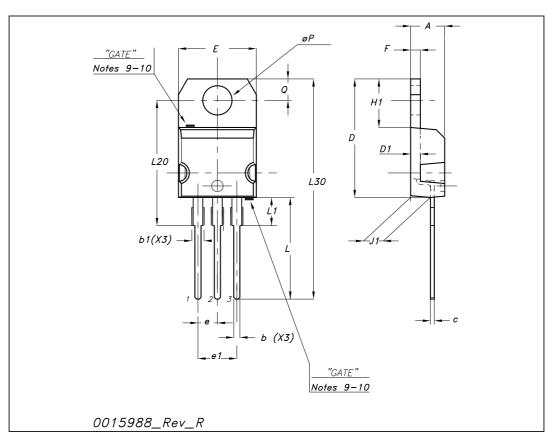
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



Dim		mm			inch		
DIM	Min	Тур	Max	Min	Тур	Мах	
А	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.14		1.70	0.044		0.066	
С	0.48		0.70	0.019		0.027	
D	15.25		15.75	0.6		0.62	
D1		1.27			0.050		
E	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.051	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
ØP	3.75		3.85	0.147		0.151	
Q	2.65	İ	2.95	0.104		0.116	







5 Revision history

Table 5. Document revision history

Date	Revision	Changes
21-Jun-2004	4	No history because migration
27-Oct-2008	5	Mechanical data updated.



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